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## SAM<sup>TM</sup> Data Sheet SAM-1960-54-10ps-x, $\lambda$ = 1960 nm

Laser wavelength		λ = 1960 nm
High reflection band		λ = 1900 2050 nm
Absorbance		A <sub>0</sub> = 54 %
Modulation depth		∆R = 30 %
Non-saturable loss		A <sub>ns</sub> = 24 %
Saturation fluence		$\Phi_{sat}$ = 35 µJ/cm <sup>2</sup>
Relaxation time constant		τ ~ 10 ps
Damage threshold		$\Phi$ = 800 µJ/cm <sup>2</sup>
Chip area		4.0 mm x 4.0 mm; other dimensions on request
Chip thickness		450 μm
Protection		the SAM is protected with a dielectric front layer
Mounting option x denotes the type of mounting as follows: x = 0 unmounted x = 12.7  g glued on a gold plated Cu-cylinder with 12.7 mm Ø		
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<b>x</b> = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $arnothing$
<b>x</b> = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
<b>x</b> = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
<b>x</b> = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
<b>x</b> = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

